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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	-
Number of I/O	822
Number of Gates	-
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	1508-BBGA, FCBGA
Supplier Device Package	1508-FBGA (30x30)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=ep1s40f1508c7n

Chapter	Date/Version	Changes Made
4	January 2005, 3.2	<ul style="list-style-type: none"> ● Updated rise and fall input values.
	September 2004, v3.1	<ul style="list-style-type: none"> ● Updated Note 3 in Table 4–8 on page 4–4. ● Updated Table 4–10 on page 4–6. ● Updated Table 4–20 on page 4–12 through Table 4–23 on page 4–13. Added rows $V_{IL(AC)}$ and $V_{IH(AC)}$ to each table. ● Updated Table 4–26 on page 4–14 through Table 4–29 on page 4–15. ● Updated Table 4–31 on page 4–16. ● Updated description of “External Timing Parameters” on page 4–33. ● Updated Table 4–36 on page 4–20. ● Added signals t_{OUTCO}, T_{XZ}, and T_{ZX} to Figure 4–4 on page 4–33. ● Added rows $t_{M512CLKENSU}$ and $t_{M512CLKENH}$ to Table 4–40 on page 4–24. ● Added rows $t_{M4CLKENSU}$ and $t_{M4CLKENH}$ to Table 4–41 on page 4–24. ● Updated Note 2 in Table 4–54 on page 4–35. ● Added rows $t_{MRAMCLKENSU}$ and $t_{MRAMCLKENH}$ to Table 4–42 on page 4–25. ● Updated Table 4–46 on page 4–29. ● Updated Table 4–47 on page 4–29.

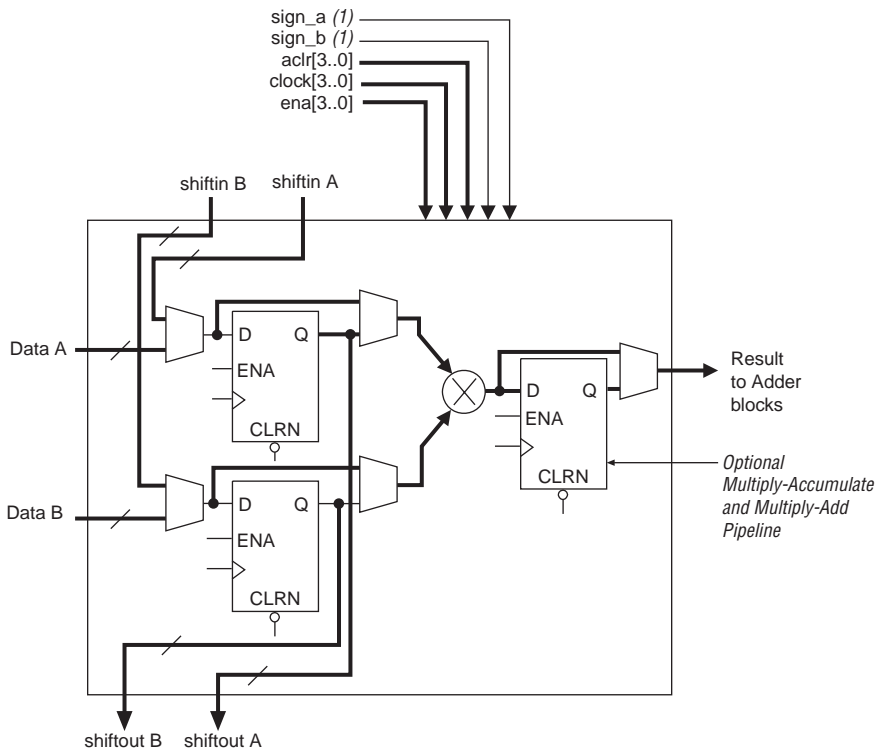
The DSP block consists of the following elements:

- Multiplier block
- Adder/output block

Multiplier Block

The DSP block multiplier block consists of the input registers, a multiplier, and pipeline register for pipelining multiply-accumulate and multiply-add/subtract functions as shown in [Figure 2–32](#).

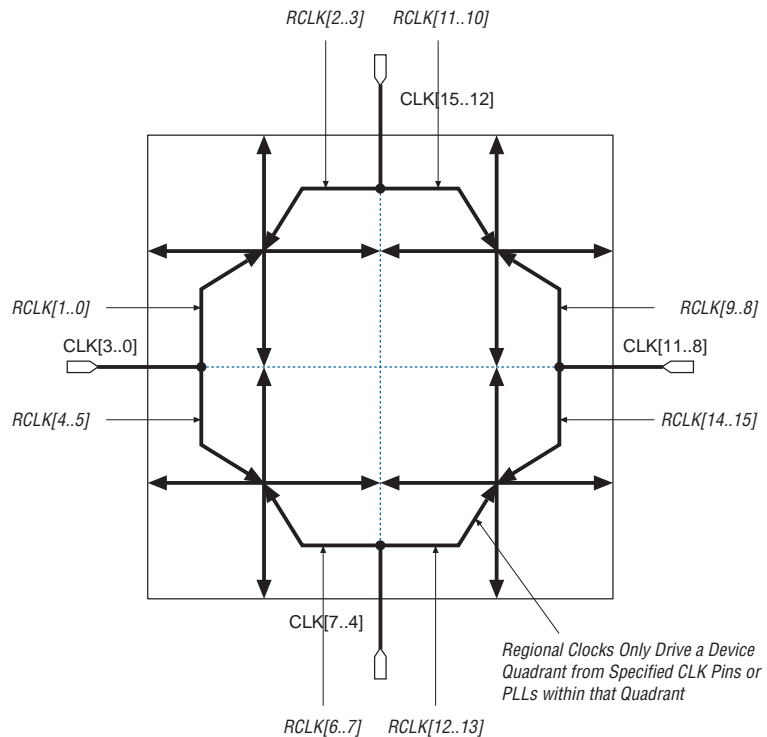
Figure 2–32. Multiplier Sub-Block within Stratix DSP Block



Note to [Figure 2–32](#):

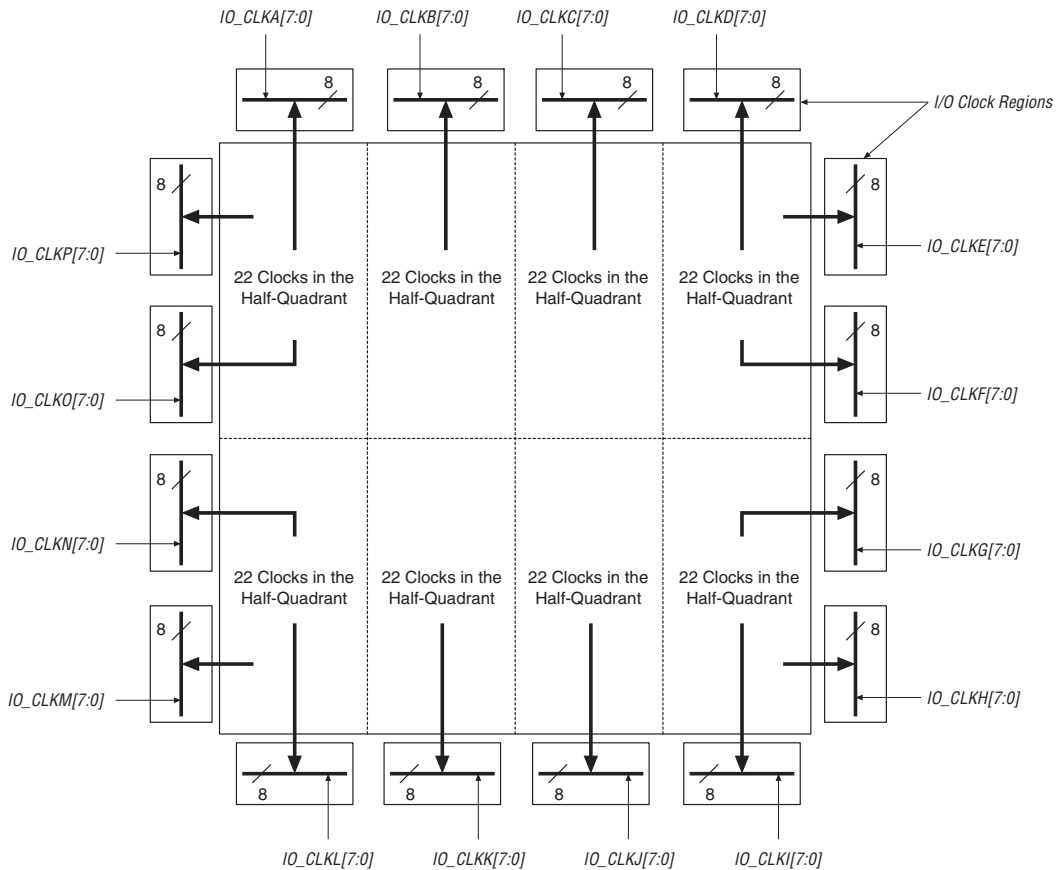
- (1) These signals can be unregistered or registered once to match data path pipelines if required.

Figure 2–43. Regional Clocks



Fast Regional Clock Network

In EP1S25, EP1S20, and EP1S10 devices, there are two fast regional clock networks, FCLK [1 . . 0] , within each quadrant, fed by input pins that can connect to fast regional clock networks (see Figure 2–44). In EP1S30 and larger devices, there are two fast regional clock networks within each half-quadrant (see Figure 2–45). Dual-purpose FCLK pins drive the fast clock networks. All devices have eight FCLK pins to drive fast regional clock networks. Any I/O pin can drive a clock or control signal onto any fast regional clock network with the addition of a delay. This signal is driven via the I/O interconnect. The fast regional clock networks can also be driven from internal logic elements.

Figure 2–48. EP1S30, EP1S40, EP1S60, EP1S80 Device I/O Clock Groups

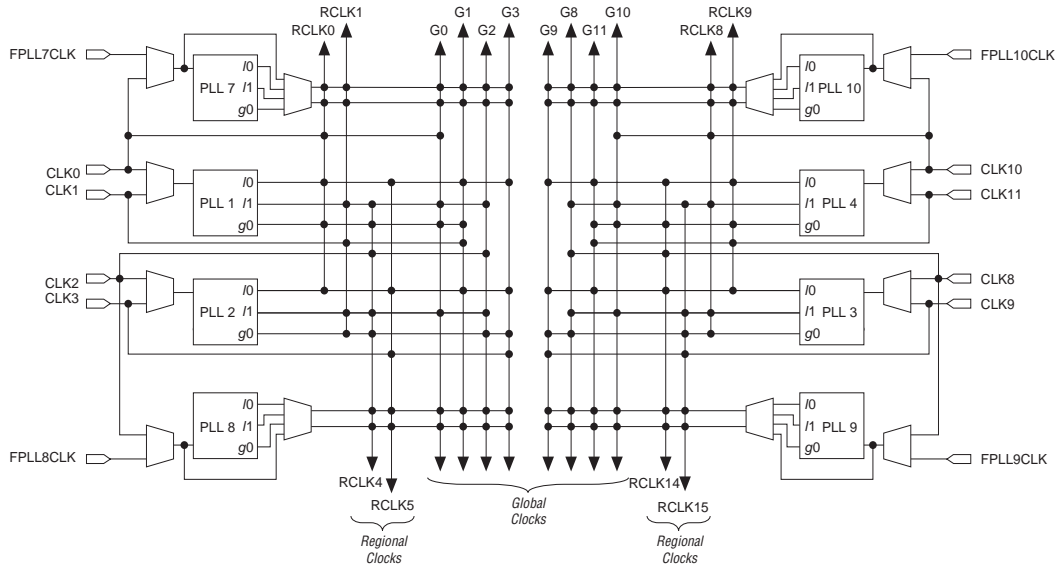
You can use the Quartus II software to control whether a clock input pin is either global, regional, or fast regional. The Quartus II software automatically selects the clocking resources if not specified.

Enhanced & Fast PLLs

Stratix devices provide robust clock management and synthesis using up to four enhanced PLLs and eight fast PLLs. These PLLs increase performance and provide advanced clock interfacing and clock-frequency synthesis. With features such as clock switchover, spread spectrum clocking, programmable bandwidth, phase and delay control, and PLL reconfiguration, the Stratix device's enhanced PLLs provide you with complete control of your clocks and system timing. The fast PLLs

Figure 2–50 shows the global and regional clocking from the PLL outputs and the CLK pins.

Figure 2–50. Global & Regional Clock Connections from Side Pins & Fast PLL Outputs Note (1), (2)



Notes to Figure 2–50:

- (1) PLLs 1 to 4 and 7 to 10 are fast PLLs. PLLs 5, 6, 11, and 12 are enhanced PLLs.
- (2) The global or regional clocks in a fast PLL's quadrant can drive the fast PLL input. A pin or other PLL must drive the global or regional source. The source cannot be driven by internally generated logic before driving the fast PLL.

Figure 2–51 shows the global and regional clocking from enhanced PLL outputs and top CLK pins.

During switchover, the PLL VCO continues to run and will either slow down or speed up, generating frequency drift on the PLL outputs. The clock switchover transitions without any glitches. After the switch, there is a finite resynchronization period to lock onto new clock as the VCO ramps up. The exact amount of time it takes for the PLL to relock relates to the PLL configuration and may be adjusted by using the programmable bandwidth feature of the PLL. The specification for the maximum time to relock is 100 μ s.



For more information on clock switchover, see *AN 313, Implementing Clock Switchover in Stratix & Stratix GX Devices*.

PLL Reconfiguration

The PLL reconfiguration feature enables system logic to change Stratix device enhanced PLL counters and delay elements without reloading a Programmer Object File (.pof). This provides considerable flexibility for frequency synthesis, allowing real-time PLL frequency and output clock delay variation. You can sweep the PLL output frequencies and clock delay in prototype environments. The PLL reconfiguration feature can also dynamically or intelligently control system clock speeds or t_{CO} delays in end systems.

Clock delay elements at each PLL output port implement variable delay. [Figure 2-54](#) shows a diagram of the overall dynamic PLL control feature for the counters and the clock delay elements. The configuration time is less than 20 μ s for the enhanced PLL using a input shift clock rate of 22 MHz. The charge pump, loop filter components, and phase shifting using VCO phase taps cannot be dynamically adjusted.

Table 2–28 shows the possible settings for the I/O standards with drive strength control.

I/O Standard	I_{OH} / I_{OL} Current Strength Setting (mA)
3.3-V LVTTTL	24 (1), 16, 12, 8, 4
3.3-V LVCMOS	24 (2), 12 (1), 8, 4, 2
2.5-V LVTTTL/LVCMOS	16 (1), 12, 8, 2
1.8-V LVTTTL/LVCMOS	12 (1), 8, 2
1.5-V LVCMOS	8 (1), 4, 2
GTL/GTL+ 1.5-V HSTL Class I and II 1.8-V HSTL Class I and II SSTL-3 Class I and II SSTL-2 Class I and II SSTL-18 Class I and II	Support max and min strength

Notes to Table 2–28:

- (1) This is the Quartus II software default current setting.
- (2) I/O banks 1, 2, 5, and 6 do not support this setting.

Quartus II software version 4.2 and later will report current strength as “PCI Compliant” for 3.3-V PCI, 3.3-V PCI-X 1.0, and Compact PCI I/O standards.

Stratix devices support series on-chip termination (OCT) using programmable drive strength. For more information, contact your Altera Support Representative.

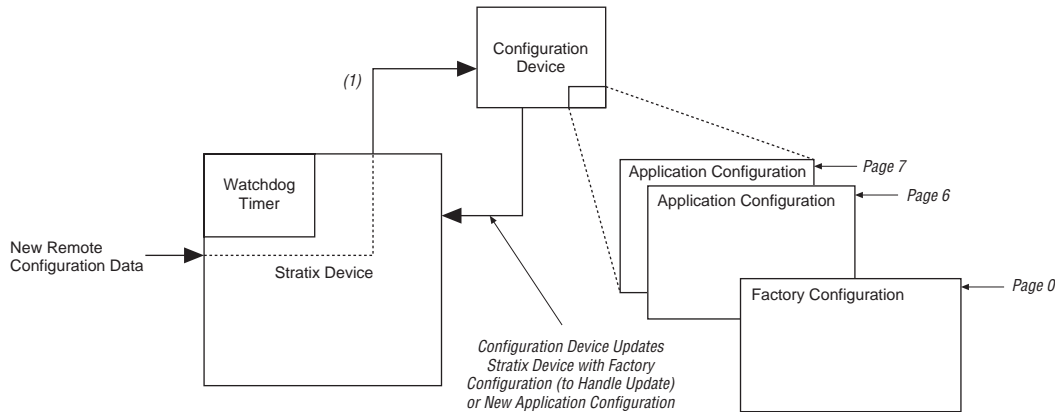
Open-Drain Output

Stratix devices provide an optional open-drain (equivalent to an open-collector) output for each I/O pin. This open-drain output enables the device to provide system-level control signals (e.g., interrupt and write-enable signals) that can be asserted by any of several devices.

Slew-Rate Control

The output buffer for each Stratix device I/O pin has a programmable output slew-rate control that can be configured for low-noise or high-speed performance. A faster slew rate provides high-speed transitions for high-performance systems. However, these fast transitions may introduce noise transients into the system. A slow slew rate reduces system noise, but adds a nominal delay to rising and falling edges. Each

Figure 3–2. Stratix Device Remote Update



Note to Figure 3–2:

- (1) When the Stratix device is configured with the factory configuration, it can handle update data from EPC16, EPC8, or EPC4 configuration device pages and point to the next page in the configuration device.
-

Table 4–22. SSTL-3 Class I Specifications (Part 2 of 2)

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
$V_{IL(AC)}$	Low-level AC input voltage				$V_{REF} - 0.4$	V
V_{OH}	High-level output voltage	$I_{OH} = -8 \text{ mA}$ (3)	$V_{TT} + 0.6$			V
V_{OL}	Low-level output voltage	$I_{OL} = 8 \text{ mA}$ (3)			$V_{TT} - 0.6$	V

Table 4–23. SSTL-3 Class II Specifications

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V_{CCIO}	Output supply voltage		3.0	3.3	3.6	V
V_{TT}	Termination voltage		$V_{REF} - 0.05$	V_{REF}	$V_{REF} + 0.05$	V
V_{REF}	Reference voltage		1.3	1.5	1.7	V
$V_{IH(DC)}$	High-level DC input voltage		$V_{REF} + 0.2$		$V_{CCIO} + 0.3$	V
$V_{IL(DC)}$	Low-level DC input voltage		-0.3		$V_{REF} - 0.2$	V
$V_{IH(AC)}$	High-level AC input voltage		$V_{REF} + 0.4$			V
$V_{IL(AC)}$	Low-level AC input voltage				$V_{REF} - 0.4$	V
V_{OH}	High-level output voltage	$I_{OH} = -16 \text{ mA}$ (3)	$V_{TT} + 0.8$			V
V_{OL}	Low-level output voltage	$I_{OL} = 16 \text{ mA}$ (3)			$V_{TT} - 0.8$	V

Table 4–24. 3.3-V AGP 2× Specifications

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V_{CCIO}	Output supply voltage		3.15	3.3	3.45	V
V_{REF}	Reference voltage		$0.39 \times V_{CCIO}$		$0.41 \times V_{CCIO}$	V
V_{IH}	High-level input voltage (4)		$0.5 \times V_{CCIO}$		$V_{CCIO} + 0.5$	V
V_{IL}	Low-level input voltage (4)				$0.3 \times V_{CCIO}$	V
V_{OH}	High-level output voltage	$I_{OUT} = -0.5 \text{ mA}$	$0.9 \times V_{CCIO}$		3.6	V
V_{OL}	Low-level output voltage	$I_{OUT} = 1.5 \text{ mA}$			$0.1 \times V_{CCIO}$	V

Table 4–25. 3.3-V AGP 1× Specifications (Part 1 of 2)

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V_{CCIO}	Output supply voltage		3.15	3.3	3.45	V
V_{IH}	High-level input voltage (4)		$0.5 \times V_{CCIO}$		$V_{CCIO} + 0.5$	V
V_{IL}	Low-level input voltage (4)				$0.3 \times V_{CCIO}$	V

Timing Model

The DirectDrive™ technology and MultiTrack™ interconnect ensure predictable performance, accurate simulation, and accurate timing analysis across all Stratix device densities and speed grades. This section describes and specifies the performance, internal, external, and PLL timing specifications.

All specifications are representative of worst-case supply voltage and junction temperature conditions.

Preliminary & Final Timing

Timing models can have either preliminary or final status. The Quartus II software issues an informational message during the design compilation if the timing models are preliminary. Table 4–35 shows the status of the Stratix device timing models.

Preliminary status means the timing model is subject to change. Initially, timing numbers are created using simulation results, process data, and other known parameters. These tests are used to make the preliminary numbers as close to the actual timing parameters as possible.

Final timing numbers are based on actual device operation and testing. These numbers reflect the actual performance of the device under worst-case voltage and junction temperature conditions.

Table 4–35. Stratix Device Timing Model Status

Device	Preliminary	Final
EP1S10		✓
EP1S20		✓
EP1S25		✓
EP1S30		✓
EP1S40		✓
EP1S60		✓
EP1S80		✓

Table 4–50. M-RAM Block Internal Timing Microparameters (Part 2 of 2)

Symbol	-5		-6		-7		-8		Unit
	Min	Max	Min	Max	Min	Max	Min	Max	
$t_{MRAMBESU}$	25		25		28		33		ps
$t_{MRAMBEH}$	18		20		23		27		ps
$t_{MRAMDATAASU}$	25		25		28		33		ps
$t_{MRAMDATAAH}$	18		20		23		27		ps
$t_{MRAMADDRASU}$	25		25		28		33		ps
$t_{MRAMADDRAH}$	18		20		23		27		ps
$t_{MRAMDATABSU}$	25		25		28		33		ps
$t_{MRAMDATA BH}$	18		20		23		27		ps
$t_{MRAMADDRBSU}$	25		25		28		33		ps
$t_{MRAMADDRBH}$	18		20		23		27		ps
$t_{MRAMDATA CO1}$		1,038		1,053		1,210		1,424	ps
$t_{MRAMDATA CO2}$		4,362		4,939		5,678		6,681	ps
$t_{MRAMCLKHL}$	1,000		1,111		1,190		1,400		ps
$t_{MRAMCLR}$	135		150		172		202		ps

Table 4–51. Routing Delay Internal Timing Parameters

Symbol	-5		-6		-7		-8		Unit
	Min	Max	Min	Max	Min	Max	Min	Max	
t_{R4}		268		295		339		390	ps
t_{R8}		371		349		401		461	ps
t_{R24}		465		512		588		676	ps
t_{C4}		440		484		557		641	ps
t_{C8}		577		634		730		840	ps
t_{C16}		445		489		563		647	ps
t_{LOCAL}		313		345		396		455	ps

Routing delays vary depending on the load on that specific routing line. The Quartus II software reports the routing delay information when running the timing analysis for a design.

Table 4–93. EP1S80 External I/O Timing on Column Pins Using Global Clock Networks *Note (1)*

Parameter	-5 Speed Grade		-6 Speed Grade		-7 Speed Grade		-8 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	Min	Max	
t_{INSU}	0.884		0.976		1.118		NA		ns
t_{INH}	0.000		0.000		0.000		NA		ns
t_{OUTCO}	3.267	6.274	3.267	6.721	3.267	7.415	NA	NA	ns
t_{XZ}	3.207	6.148	3.207	6.589	3.207	7.291	NA	NA	ns
t_{ZX}	3.207	6.148	3.207	6.589	3.207	7.291	NA	NA	ns
$t_{INSUPLL}$	0.506		0.656		0.838		NA		ns
t_{INHPLL}	0.000		0.000		0.000		NA		ns
$t_{OUTCOPLL}$	1.635	2.805	1.635	2.809	1.635	2.828	NA	NA	ns
t_{XZPLL}	1.575	2.679	1.575	2.677	1.575	2.704	NA	NA	ns
t_{ZXPLL}	1.575	2.679	1.575	2.677	1.575	2.704	NA	NA	ns

Table 4–94. EP1S80 External I/O Timing on Row Pins Using Fast Regional Clock Networks *Note (1)*

Parameter	-5 Speed Grade		-6 Speed Grade		-7 Speed Grade		-8 Speed Grade		Unit
	Min	Max	Min	Max	Min	Max	Min	Max	
t_{INSU}	2.792		2.993		3.386		NA		ns
t_{INH}	0.000		0.000		0.000		NA		ns
t_{OUTCO}	2.619	5.235	2.619	5.609	2.619	6.086	NA	NA	ns
t_{XZ}	2.646	5.289	2.646	5.665	2.646	6.154	NA	NA	ns
t_{ZX}	2.646	5.289	2.646	5.665	2.646	6.154	NA	NA	ns

the FPGA device. The Quartus II software calculates the I/O timing for each I/O standard with a default baseline loading as specified by the I/O standard.

Altera measures clock-to-output delays (t_{CO}) at worst-case process, minimum voltage, and maximum temperature (PVT) for the 3.3-V LVTTTL I/O standard with 24 mA (default case) current drive strength setting and fast slew rate setting. I/O adder delays are measured to calculate the t_{CO} change at worst-case PVT across all I/O standards and current drive strength settings with the default loading shown in [Table 4-101 on page 4-62](#). Timing derating data for additional loading is taken for t_{CO} across worst-case PVT for all I/O standards and drive strength settings. These three pieces of data are used to predict the timing at the output pin.

$$t_{CO} \text{ at pin} = t_{OUTCO} \text{ max for 3.3-V 24 mA LVTTTL} + \text{I/O Adder} + \text{Output Delay Adder for Loading}$$

Simulation using IBIS models is required to determine the delays on the PCB traces in addition to the output pin delay timing reported by the Quartus II software and the timing model in the device handbook.

1. Simulate the output driver of choice into the generalized test setup using values from [Table 4-101 on page 4-62](#).
2. Record the time to VMEAS.
3. Simulate the output driver of choice into the actual PCB trace and load, using the appropriate IBIS input buffer model or an equivalent capacitance value to represent the load.
4. Record the time to VMEAS.
5. Compare the results of steps 2 and 4. The increase or decrease in delay should be added to or subtracted from the I/O Standard Output Adder delays to yield the actual worst-case propagation delay (clock-to-input) of the PCB trace.

The Quartus II software reports maximum timing with the conditions shown in [Table 4-101 on page 4-62](#) using the preceding equation. [Figure 4-7 on page 4-62](#) shows the model of the circuit that is represented by the Quartus II output timing.

Table 4–125. High-Speed I/O Specifications for Flip-Chip Packages (Part 4 of 4) Notes (1), (2)														
Symbol	Conditions	-5 Speed Grade			-6 Speed Grade			-7 Speed Grade			-8 Speed Grade			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
t _{DUTY}	LVDS (J = 2 through 10)	47.5	50	52.5	47.5	50	52.5	47.5	50	52.5	47.5	50	52.5	%
	LVDS (J = 1) and LVPECL, PCML, HyperTransport technology	45	50	55	45	50	55	45	50	55	45	50	55	%
t _{LOCK}	All			100			100			100			100	μs

Notes to Table 4–125:

- (1) When J = 4, 7, 8, and 10, the SERDES block is used.
- (2) When J = 2 or J = 1, the SERDES is bypassed.

Table 4–130. Enhanced PLL Specifications for -8 Speed Grade (Part 2 of 3)

Symbol	Parameter	Min	Typ	Max	Unit
$t_{\text{EINJITTER}}$	External feedback clock period jitter			± 200 (3)	ps
t_{FCOMP}	External feedback clock compensation time (4)			6	ns
f_{OUT}	Output frequency for internal global or regional clock	0.3		357	MHz
$f_{\text{OUT_EXT}}$	Output frequency for external clock (3)	0.3		369	MHz
t_{OUTDUTY}	Duty cycle for external clock output (when set to 50%)	45		55	%
t_{JITTER}	Period jitter for external clock output (6)			± 100 ps for >200-MHz outclk ± 20 mUI for <200-MHz outclk	ps or mUI
$t_{\text{CONFIG5,6}}$	Time required to reconfigure the scan chains for PLLs 5 and 6			$289/f_{\text{SCANCLK}}$	
$t_{\text{CONFIG11,12}}$	Time required to reconfigure the scan chains for PLLs 11 and 12			$193/f_{\text{SCANCLK}}$	
t_{SCANCLK}	scanclk frequency (5)			22	MHz
t_{DLOCK}	Time required to lock dynamically (after switchover or reconfiguring any non-post-scale counters/delays) (7) (11)	(9)		100	μs
t_{LOCK}	Time required to lock from end of device configuration (11)	10		400	μs
f_{VCO}	PLL internal VCO operating range	300		600 (8)	MHz

Tables 4–131 through 4–133 describe the Stratix device fast PLL specifications.

Table 4–131. Fast PLL Specifications for -5 & -6 Speed Grade Devices

Symbol	Parameter	Min	Max	Unit
f_{IN}	CLKIN frequency (1), (2), (3)	10	717	MHz
f_{INPFD}	Input frequency to PFD	10	500	MHz
f_{OUT}	Output frequency for internal global or regional clock (3)	9.375	420	MHz
f_{OUT_DIFFIO}	Output frequency for external clock driven out on a differential I/O data channel (2)	(5)	(5)	
f_{VCO}	VCO operating frequency	300	1,000	MHz
t_{INDUTY}	CLKIN duty cycle	40	60	%
$t_{INJITTER}$	Period jitter for CLKIN pin		±200	ps
t_{DUTY}	Duty cycle for DFFIO 1 × CLKOUT pin (6)	45	55	%
t_{JITTER}	Period jitter for DIFFIO clock out (6)		(5)	ps
t_{LOCK}	Time required for PLL to acquire lock	10	100	μs
m	Multiplication factors for m counter (6)	1	32	Integer
l_0, l_1, g_0	Multiplication factors for l_0, l_1 , and g_0 counter (7), (8)	1	32	Integer
t_{ARESET}	Minimum pulse width on areset signal	10		ns

Table 4–132. Fast PLL Specifications for -7 Speed Grades (Part 1 of 2)

Symbol	Parameter	Min	Max	Unit
f_{IN}	CLKIN frequency (1), (3)	10	640	MHz
f_{INPFD}	Input frequency to PFD	10	500	MHz
f_{OUT}	Output frequency for internal global or regional clock (4)	9.375	420	MHz
f_{OUT_DIFFIO}	Output frequency for external clock driven out on a differential I/O data channel	(5)	(5)	MHz
f_{VCO}	VCO operating frequency	300	700	MHz
t_{INDUTY}	CLKIN duty cycle	40	60	%
$t_{INJITTER}$	Period jitter for CLKIN pin		±200	ps
t_{DUTY}	Duty cycle for DFFIO 1 × CLKOUT pin (6)	45	55	%

Table 4–133. Fast PLL Specifications for -8 Speed Grades (Part 2 of 2)

Symbol	Parameter	Min	Max	Unit
t_{ARESET}	Minimum pulse width on areset signal	10		ns

Notes to Tables 4–131 through 4–133:

- (1) See “Maximum Input & Output Clock Rates” on page 4–76.
- (2) PLLs 7, 8, 9, and 10 in the EP1S80 device support up to 717-MHz input and output.
- (3) Use this equation ($f_{OUT} = f_{IN} * ml(n \times \text{post-scale counter})$) in conjunction with the specified f_{INPFD} and f_{VCO} ranges to determine the allowed PLL settings.
- (4) When using the SERDES, high-speed differential I/O mode supports a maximum output frequency of 210 MHz to the global or regional clocks (that is, the maximum data rate 840 Mbps divided by the smallest SERDES J factor of 4).
- (5) Refer to the section “High-Speed I/O Specification” on page 4–87 for more information.
- (6) This parameter is for high-speed differential I/O mode only.
- (7) These counters have a maximum of 32 if programmed for 50/50 duty cycle. Otherwise, they have a maximum of 16.
- (8) High-speed differential I/O mode supports $W = 1$ to 16 and $J = 4, 7, 8,$ or 10.

DLL Specifications

Table 4–134 reports the jitter for the DLL in the DQS phase shift reference circuit.

Table 4–134. DLL Jitter for DQS Phase Shift Reference Circuit

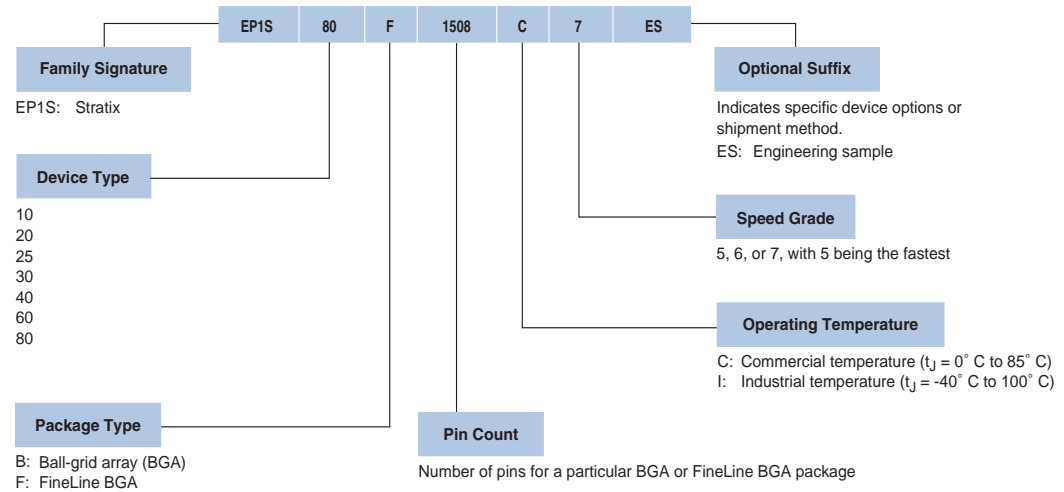
Frequency (MHz)	DLL Jitter (ps)
197 to 200	± 100
160 to 196	± 300
100 to 159	± 500



For more information on DLL jitter, see the *DDR SRAM* section in the *Stratix Architecture* chapter of the *Stratix Device Handbook, Volume 1*.

Table 4–135 lists the Stratix DLL low frequency limit for full phase shift across all PVT conditions. The Stratix DLL can be used below these frequencies, but it will not achieve the full phase shift requested across all

Figure 5–1. Stratix Device Packaging Ordering Information



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